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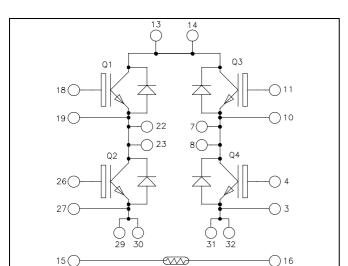


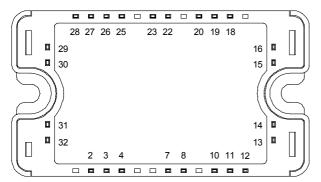






Full - Bridge Trench + Field Stop IGBT3 Power Module





All multiple inputs and outputs must be shorted together Example: 13/14; 29/30; 22/23 ...

$V_{CES} = 600V$ $I_C = 75A$ @ $T_C = 80^{\circ}C$

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Trench + Field Stop IGBT3 Technology
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
 - Symmetrical design
 - High level of integration
- Internal thermistor for temperature monitoring

Benefits

- Stable temperature behavior
- Very rugged
- Solderable terminals for easy PCB mounting
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- Low profile
- Each leg can be easily paralleled to achieve a phase leg of twice the current capability
- RoHS compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		600	V
ī	Continuous Collector Current	$T_C = 25^{\circ}C$	100	
$I_{\rm C}$	Continuous Conector Current	$T_C = 80$ °C	75	A
I_{CM}	Pulsed Collector Current	$T_C = 25^{\circ}C$	140	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_C = 25^{\circ}C$	250	W
RBSOA	Reverse Bias Safe Operating Area	$T_{\rm J} = 150^{\circ}{\rm C}$	150A @ 550V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 600V$				250	μA
V	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25$ °C		1.5	1.9	V
$V_{\text{CE(sat)}}$	Conector Emitter Saturation Voltage	$I_C = 75A$	$T_j = 150$ °C		1.7		·
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C =$	600μΑ	5.0	5.8	6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE}$	= 0V			600	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$			4620		
C_{oes}	Output Capacitance	$V_{CE} = 25V$			300		pF
C_{res}	Reverse Transfer Capacitance	f = 1MHz			140		l
$T_{d(on)}$	Turn-on Delay Time	Inductive Switch	ing (25°C)		110		
T_{r}	Rise Time		$V_{GE} = \pm 15V$		45		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 300V$ $I_{\text{C}} = 75A$			200		ns
$T_{\rm f}$	Fall Time	$R_G = 4.7\Omega$			40		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switch $V_{GE} = \pm 15V$	ing (150°C)		120		
T_{r}	Rise Time	$V_{\text{GE}} = \pm 13 \text{ V}$ $V_{\text{Bus}} = 300 \text{ V}$			50		ns
$T_{d(off)}$	Turn-off Delay Time	$I_C = 75A$			250		
T_{f}	Fall Time	$R_G = 4.7\Omega$			60		
Eon	Turn-on Switching Energy	$V_{GE} = \pm 15V$	$T_j = 25$ °C		0.35		mJ
Lon	Turn-on Switching Energy	$V_{Bus} = 300V$	$T_j = 150$ °C		0.6		1113
E _{off}	Turn-off Switching Energy	$I_{\rm C} = 75 A$ $R_{\rm G} = 4.7 \Omega$	$T_j = 25^{\circ}C$		2.2		mJ
Lon		NG - 4./22	$T_j = 150$ °C		2.6		1

Reverse diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit	
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			600			V	
V _{RRM} Ma I _{RM} Ma I _F DC V _F Dic t _{rr} Rev	Maximum Reverse Leakage Current	V-=600V	$T_j = 25$ °C			250	^	
1 _{RM}	Waximum Reverse Leakage Current	$\begin{array}{c c} V_R = 600V & \hline & T_j = \\ \hline & T_C = \\ \hline & T_F = 75A & T_j = \\ \hline & V_{GE} = 0V & T_j = \\ \hline & T_$	$T_{j} = 150^{\circ}C$	$T_{j} = 150^{\circ}C$			500	μΑ
I_F	DC Forward current		Tc = 80°C		75		Α	
V_{r}	Diode Forward Voltage	$I_F = 75A$	$T_i = 25$ °C		1.6	2		
V F	Blode I of ward Voltage	$V_{GE} = 0V$	$T_{i} = 150^{\circ}C$		1.5		V	
t	Reverse Recovery Time		$T_j = 25$ °C		100		ns	
۲r	Reverse Recovery Time	$T_{i} = 150^{\circ}C$		150		113		
0	Reverse Recovery Charge	-	$T_j = 25^{\circ}C$		3.6		пС	
Qrr		$T_{j} = 150^{\circ}C$		7.6		μС		
Б	Payarga Pagayary Engray		$T_i = 25^{\circ}C$		0.85		m I	
\mathbf{c}_{r}	Reverse Recovery Energy		$T_j = 150$ °C		1.8		mJ	



 $Temperature\ sensor\ NTC\ (\text{see application note APT0406 on www.microsemi.com for more information}).$

Symbol	Characteristic	Min	Тур	Max	Unit	
R ₂₅	Resistance @ 25°C		50		kΩ	l
${ m B}_{25/85}$	$T_{25} = 298.15 \text{ K}$		3952		K	l

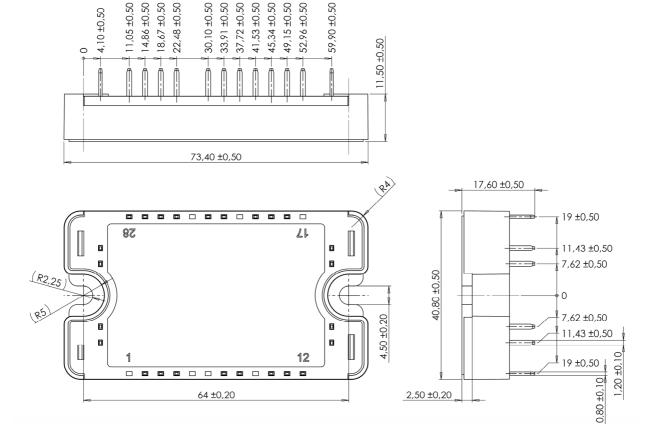
$$R_{T} = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature}$$

$$R_{T}: \text{ Thermistor value at T}$$

Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit	
R_{thJC}	Junction to Case Thermal Resistance		IGBT			0.60	°C/W	
TthJC	Junction to Case Thermal Resistance		Diode			0.98	C/ VV	
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V	
$T_{\rm J}$	Operating junction temperature range		-40		175			
T_{STG}	Storage Temperature Range		-40		125	°C		
$T_{\rm C}$	Operating Case Temperature			-40		100		
Torque	Mounting torque	To heatsink	M4	2		3	N.m	
Wt	Package Weight					110	g	

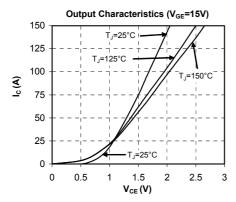
SP3 Package outline (dimensions in mm)

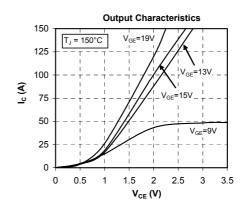


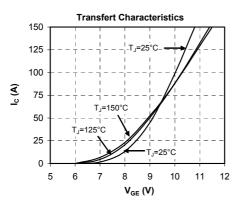
See application note 1901 - Mounting Instructions for SP3 Power Modules on www.microsemi.com

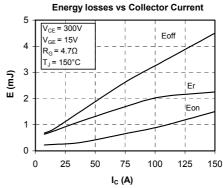


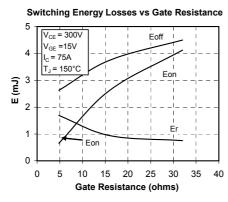
Typical Performance Curve

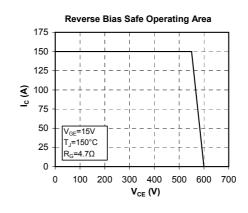


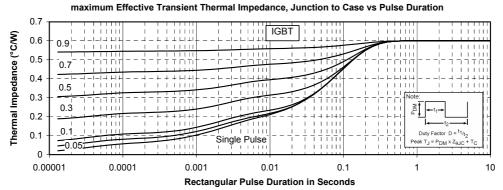




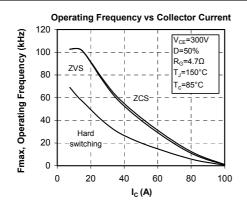


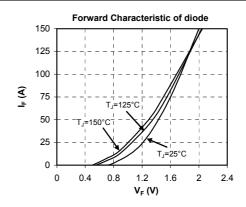


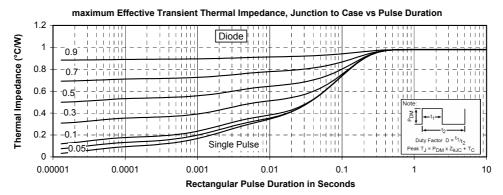












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